

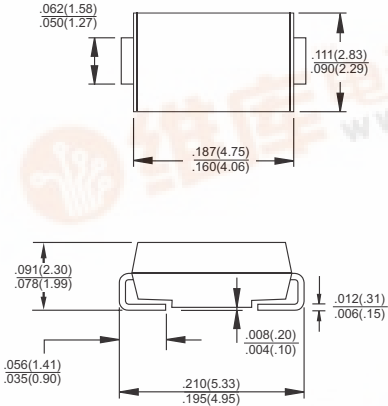


<div>TSC</div> <div></div>	<div>SS115</div> <div>1.0 AMP. Surface Mount Schottky Barrier Rectifiers</div>																																																		
<div></div>	<div>Voltage Range</div> <div>150 Volts</div> <div>Current</div> <div>1.0 Ampere</div>																																																		
<div>Features</div> <div><ul style="list-style-type: none">For surface mounted applicationMetal to silicon rectifier, majority carrier conductionLow forward voltage dropEasy pick and placeHigh surge current capabilityPlastic material used carriers Underwriters Laboratory Classification 94V-OEpitaxial constructionHigh temperature soldering: 260°C/ 10 seconds at terminals</div>	<div>SMA/DO-214AC</div> <div></div> <div>Dimensions in inches and (millimeters)</div>																																																		
	<div>Mechanical Data</div> <div><ul style="list-style-type: none">Case: Molded plasticTerminals: Solder platedPolarity: Indicated by cathode bandPackaging: 12mm tape per EIA STD RS-481Weight: 0.064 gram</div>																																																		
<div>Maximum Ratings and Electrical Characteristics</div> <div>Rating at 25°C ambient temperature unless otherwise specified.</div> <div>Single phase, half wave, 60 Hz, resistive or inductive load.</div> <div>For capacitive load, derate current by 20%</div> <table><tr><th>Type Number</th><th>Symbol</th><th>SS115</th><th>Units</th></tr><tr><td>Maximum Recurrent Peak Reverse Voltage</td><td>V_{RRM}</td><td>150</td><td>V</td></tr><tr><td>Maximum RMS Voltage</td><td>V_{RMS}</td><td>105</td><td>V</td></tr><tr><td>Maximum DC Blocking Voltage</td><td>V_{DC}</td><td>150</td><td>V</td></tr><tr><td>Maximum Average Forward Rectified Current at T_L (See Fig. 1)</td><td>$I_{(AV)}$</td><td>1.0</td><td>A</td></tr><tr><td>Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)</td><td>I_{FSM}</td><td>30</td><td>A</td></tr><tr><td>Maximum Instantaneous Forward Voltage (Note 1) @ 25°C 1.0A @ 125°C 1.0A @ 25°C 2.0A @ 125°C 2.0A</td><td>V_F</td><td>0.82 0.67 0.89 0.75</td><td>V</td></tr><tr><td>Maximum DC Reverse Current @ $T_A=25^{\circ}C$ at Rated DC Blocking Voltage @ $T_A=125^{\circ}C$</td><td>I_R</td><td>0.05 0.5</td><td>mA mA</td></tr><tr><td>Typical Junction Capacitance (Note 3)</td><td>C_j</td><td>50</td><td>pF</td></tr><tr><td>Typical Thermal Resistance (Note 2)</td><td>$R_{\theta JL}$</td><td>20</td><td>°C/W</td></tr><tr><td>Operating Temperature Range</td><td>T_J</td><td>-65 to +150</td><td>°C</td></tr><tr><td>Storage Temperature Range</td><td>T_{STG}</td><td>-65 to +150</td><td>°C</td></tr></table>				Type Number	Symbol	SS115	Units	Maximum Recurrent Peak Reverse Voltage	V_{RRM}	150	V	Maximum RMS Voltage	V_{RMS}	105	V	Maximum DC Blocking Voltage	V_{DC}	150	V	Maximum Average Forward Rectified Current at T_L (See Fig. 1)	$I_{(AV)}$	1.0	A	Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	30	A	Maximum Instantaneous Forward Voltage (Note 1) @ 25°C 1.0A @ 125°C 1.0A @ 25°C 2.0A @ 125°C 2.0A	V_F	0.82 0.67 0.89 0.75	V	Maximum DC Reverse Current @ $T_A=25^{\circ}C$ at Rated DC Blocking Voltage @ $T_A=125^{\circ}C$	I_R	0.05 0.5	mA mA	Typical Junction Capacitance (Note 3)	C_j	50	pF	Typical Thermal Resistance (Note 2)	$R_{\theta JL}$	20	°C/W	Operating Temperature Range	T_J	-65 to +150	°C	Storage Temperature Range	T_{STG}	-65 to +150	°C
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Notes: 1. Pulse Test with PW=300 usec, 1% Duty Cycle
2. Measured on P.C.Board with 0.2 x 0.2" (5.0 x 5.0mm) Copper Pad Areas.
3. Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C



RATINGS AND CHARACTERISTIC CURVES (SS115)

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

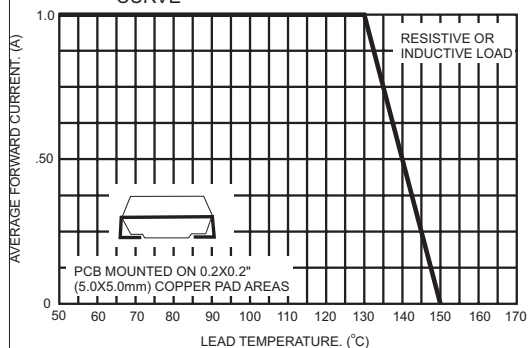


FIG.2- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

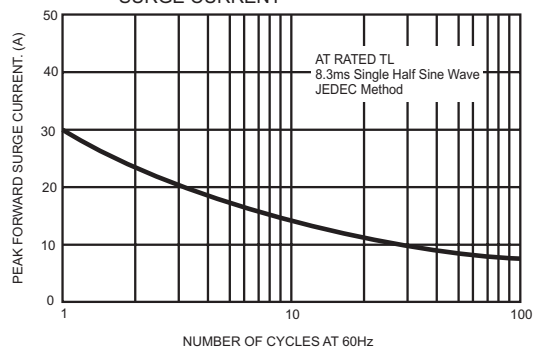


FIG.3- TYPICAL FORWARD CHARACTERISTICS

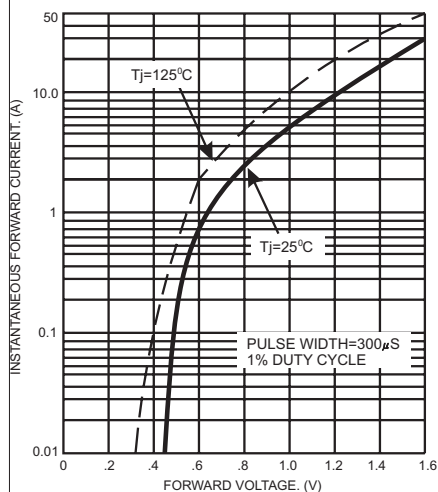


FIG.4- TYPICAL REVERSE CHARACTERISTICS

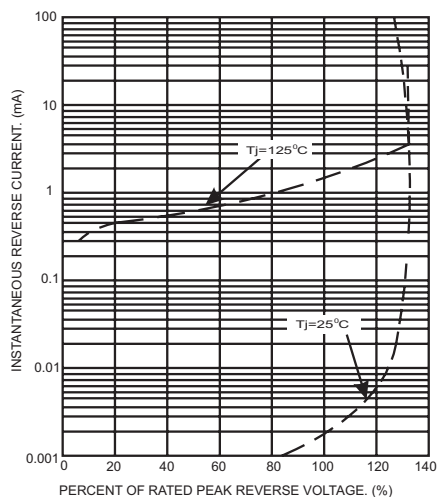


FIG.5- TYPICAL JUNCTION CAPACITANCE

